

SGLS198B-SEPTEMBER 2004-REVISED MAY 2013

DUAL MICROPOWER LinCMOS™ VOLTAGE COMPARATOR

Check for Samples: TLC393-Q1

APPLICATIONS

Automotive Applications

FEATURES

- **Qualified for Automotive Applications**
- AEC Q100 Qualified with the Following **Results:**
 - Device Temperature Grade 1: –40°C to 125°C Ambient Operating Temperature Range
 - Device HBM ESD Classification Level H2
 - Device CDM ESD Classification Level C4B
- **ESD Protection Exceeds 500 V Per** MIL-STD-883, Method 3015; Exceeds 50 V Using Machine Model (C = 200 pF, R = 0)
- Low Power: 110 µW Typ at 5 V •
- Fast Response Time: t_{PLH} = 2.5 µs Typ With 5mV Overdrive
- Single Supply Operation:
 - TLC393Q: 4 V to 16 V

DESCRIPTION

The TLC393 consists of dual independent micropower voltage comparators designed to operate from a single supply. It is functionally similar to the LM393 but uses one-twentieth the power for similar response times. The open-drain MOS output stage interfaces to a variety of loads and supplies. For a similar device with a push-pull output configuration see the TLC3702 data sheet.

Texas Instruments LinCMOS[™] process offers superior analog performance to standard CMOS processes. Along with the standard CMOS advantages of low power without sacrificing speed, high input impedance, and low bias currents, the LinCMOS™ process offers extremely stable input offset voltages, even with differential input stresses of several volts. This characteristic makes it possible to build reliable CMOS comparators.

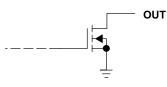
The TLC393Q is characterized for operation over the full automotive temperature range of $T_A = -40^{\circ}$ C to 125°C

T _A	V _{IO} max AT 25°C	PACK	ORDERABLE PART NUMBER	TOP-SIDE MARKING					
-40°C to 125°C	5 mV	SOIC (D)	Tape and reel	TLC393QDRQ1	C393Q1				

For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI (1)web site at http://www.ti.com.

Package drawings, thermal data, and symbolization are available at http://www.ti.com/packaging. (2)

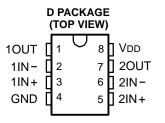
Schematic



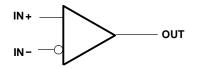
OPEN-DRAIN CMOS OUTPUT

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. LinCMOS is a trademark of Texas Instruments.

ODDEDING INFORMATION(1)



symbol (each comparator)



TLC393-Q1

SGLS198B-SEPTEMBER 2004-REVISED MAY 2013

www.ti.com



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

		VAI	_UE	UNIT
		MIN	MAX	UNIT
Supply voltage range, V _{DD} ⁽²⁾		-0.3	18	V
Differential input voltage, V _{ID} ⁽³⁾		±18	V	
Input voltage range, V _I		-0.3	V _{DD}	V
Output voltage range, V _O		-0.3	16	V
Input current, I _I		±5	mA	
Output current, I _O		20	mA	
Total supply current into V _{DD}		40	mA	
Total current out of GND		40	mA	
Package thermal impedance, θ_{JA} ⁽⁴⁾ , ⁽⁵⁾)	D Package		126	°C/W
Package mermai impedance, _{0JA} (*, (*))	PW Package		149	°C/W
Flashashia diasharra (FCD)	Human Body Model (HBM) AEC-Q100 Classification Level H2		2	kV
Electrostatic discharge (ESD)	Charge Device Model (CDM) AEC-Q100 Classification Level C4B		750	V
Operating free-air temperature range		-40	125	°C
Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values, except differential voltages, are with respect to network ground.

(3) Differential voltages are at IN+ with respect to IN -

- (4) Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
- (5) The package thermal impedance is calculated in accordance with JESD 51-7.

RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range (unless otherwise noted)

	MIN	NOM	MAX	UNIT
Supply voltage, V _{DD}	4	5	16	V
Common-mode input voltage, VIC	0		V _{DD} - 1.5	V
Low-level output current, I _{OL}			20	mA
Operating free-air temperature, T _A	-40		125	°C



www.ti.com

ELECTRICAL CHARACTERISTICS

at specified operating free-air temperature, V_{DD} = 5 V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS ⁽¹⁾	T _A	MIN	TYP	MAX	UNIT	
		$VIC = V_{ICR}min,$	25°C		1.4	5		
V _{IO}	Input offset voltage	$V_{DD} = 5 V$ to 10 V, See ⁽²⁾	–40°C to 125°C			10	mV	
	Input offset current	$\lambda = 25 \lambda $	25°C		1		pА	
I _{IO}	input onset current	V _{IC} = 2.5 V	125°C			15	nA	
	Input biog ourrent		25°C		5		pА	
I _{IB}	Input bias current	$V_{IC} = 2.5 V$	125°C			30	nA	
V _{ICR}	Common-mode input voltage		25°C	0 to VDD - 1			V	
VICR	range		-40°C to 125°C	0 to VDD - 1.5			v	
			25°C		84			
CMMR	Common-mode rejection ratio	$V_{IC} = V_{ICR}min$	125°C		84		dB	
			-40°C		84			
			25°C		85		dB	
k _{SVR}	Supply-voltage rejection ratio	$V_{DD} = 5 V$ to 10 V	125°C		84			
			-40°C		84			
N/			25°C		300	400		
V _{OL}	Low-level output voltage	$V_{ID} = -1 V$, $I_{OL} = 6 mA$	125°C			800	mV	
			25°C		0.8	40	nA	
I _{ОН}	High-level output current	V _{ID} = 1 V, V _O = 5 V	125°C			1	∞A	
	Supply current (both	Outputs Issue Nie Issuel	25°C		22	40		
IDD	comparators)	Outputs low, No load	-40°C to 125°C			90	∞A	

(1) All characteristics are measured with zero common-mode voltage unless otherwise noted.
(2) The offset voltage limits given are the maximum values required to drive the output up to 4.5 V or down to 0.3 V (with a 2.5-kM load to a second sec VDD).

SWITCHING CHARACTERISTICS

 $V_{DD} = 5 \text{ V}, \text{ TA} = 25^{\circ}\text{C}$ (see Figure 3)

	PARAMETER	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
			Overdrive = 2 mV		4.5		
			Overdrive = 5 mV		2.5		∞S
t _{PLH}	Propagation delay time, low-to- high level output	f = 10 kHz, $C_1 = 15 \text{ pF}$	Overdrive = 10 mV		1.7		
			Overdrive = 20 mV		1.2		
			Overdrive = 40 mV		1.1		
		$V_I = 1.4$ -V step at IN +		1.1			
			Overdrive = 2 mV		3.6		∞S
			Overdrive = 5 mV		2.1		
t _{PHL}	Propagation delay time, high-to- low level output	f = 10 kHz, $C_1 = 15 \text{ pF}$	Overdrive = 10 mV		1.3		
			Overdrive = 20 mV		0.85		
			Overdrive = 40 mV		0.55		
		$V_I = 1.4$ -V step at IN +			0.1		
t _f	Fall time, output	f = 10 kHz, C _L = 15 pF	Overdrive = 50 mV		22		∞s

PARAMETER MEASUREMENT INFORMATION

The TLC393 contains a digital output stage which, if held in the linear region of the transfer curve, can cause damage to the device. Conventional operational amplifier/comparator testing incorporates the use of a servo loop that is designed to force the device output to a level within this linear region. Since the servo-loop method of testing cannot be used, the following alternatives for testing parameters such as input offset voltage, common-mode rejection ratio, etc., are suggested.

To verify that the input offset voltage falls within the limits specified, the limit value is applied to the input as shown in Figure 1(a). With the noninverting input positive with respect to the inverting input, the output should be high. With the input polarity reversed, the output should be low.

A similar test can be made to verify the input offset voltage at the common-mode extremes. The supply voltages can be slewed as shown in Figure 1(b) for the V_{ICR} test, rather than changing the input voltages, to provide greater accuracy.

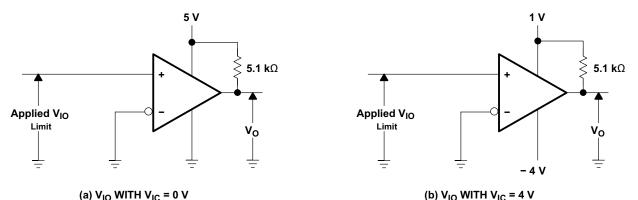


Figure 1. Method for Verifying That Input Offset Voltage Is Within Specified Limits

A close approximation of the input offset voltage can be obtained by using a binary search method to vary the differential input voltage while monitoring the output state. When the applied input voltage differential is equal, but opposite in polarity, to the input offset voltage, the output changes states.

Figure 2 illustrates a practical circuit for direct dc measurement of input offset voltage that does not bias the comparator in the linear region. The circuit consists of a switching-mode servo loop in which U1A generates a triangular waveform of approximately 20-mV amplitude. U1B acts as a buffer, with C2 and R4 removing any residual dc offset. The signal is then applied to the inverting input of the comparator under test, while the noninverting input is driven by the output of the integrator formed by U1C through the voltage divider formed by R9 and R10. The loop reaches a stable operating point when the output of the comparator under test has a duty cycle of exactly 50%, which can only occur when the incoming triangle wave is sliced symmetrically or when the voltage at the noninverting input exactly equals the input offset voltage.

The voltage divider formed by R9 and R10 provides an increase in input offset voltage by a factor of 100 to make measurement easier. The values of R5, R8, R9, and R10 can significantly influence the accuracy of the reading; therefore, it is suggested that their tolerance level be 1% or lower.

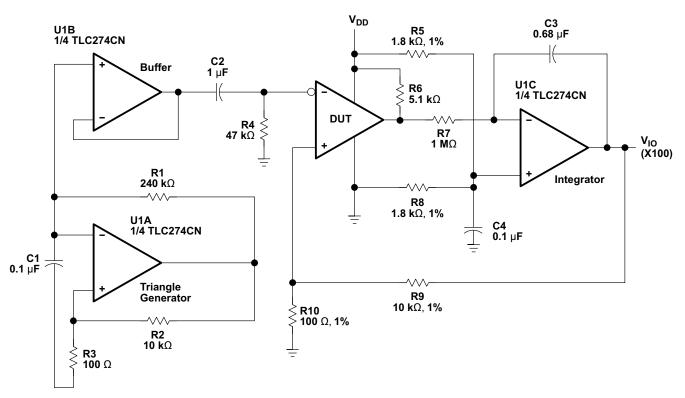
Measuring the extremely low values of input current requires isolation from all other sources of leakage current and compensation for the leakage of the test socket and board. With a good picoammeter, the socket and board leakage can be measured with no device in the socket. Subsequently, this open-socket leakage value can be subtracted from the measurement obtained with a device in the socket to obtain the actual input current of the device.

4







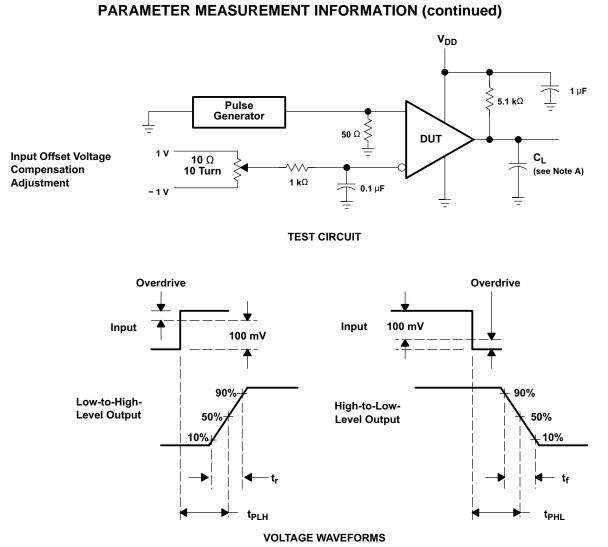


PARAMETER MEASUREMENT INFORMATION (continued)

Figure 2. Circuit for Input Offset Voltage Measurement

Propagation delay time is defined as the interval between the application of an input step function and the instant when the output reaches 50% of its maximum value. Propagation delay time, low-to-high level output, is measured from the leading edge of the input pulse, while propagation delay time, high-to-low level output, is measured from the trailing edge of the input pulse. Propagation delay time measurement at low input signal levels can be greatly affected by the input offset voltage. The offset voltage should be balanced by the adjustment at the inverting input (as shown in Figure 3) so that the circuit is just at the transition point. Then a low signal, for example, 105 mV or 5 mV overdrive, causes the output to change state.

www.ti.com



A. C_L includes probe and jig capacitance.

Figure 3. Propagation Delay, Rise Time, and Fall Time Circuit and Voltage Waveforms



www.ti.com

Table 1. Table of Graphs

			FIGURE
V _{IO}	Input offset voltage	Distribution	Figure 4
I _{IB}	Input bias current	vs Free-air temperature	Figure 5
CMRR	Common-mode rejection ratio	vs Free-air temperature	Figure 6
k _{SVR}	Supply-voltage rejection ratio	vs Free-air temperature	Figure 7
	Level and entering the sec	vs Low-level output current	Figure 8
V _{OL}	Low-level output voltage	vs Free-air temperature	Figure 9
		vs High-level output voltage	Figure 10
ЮН	Low-level output current	vs Free-air temperature	Figure 11
	Quarka summer	vs Supply voltage	Figure 12
IDD	Supply current	vs Free-air temperature	Figure 13
t _{PLH}	Low-to-high level output propagation delay time	vs Supply voltage	Figure 14
t _{PHL}	High-to-low level output propagation delay time	vs Supply voltage	Figure 15
	Low-to-high-level output response	Low-to-high level output propagation delay time	Figure 16
	High-to-low level output response	High-to-low level output propagation delay time	Figure 17
t _f	Fall time	vs Supply voltage	Figure 18

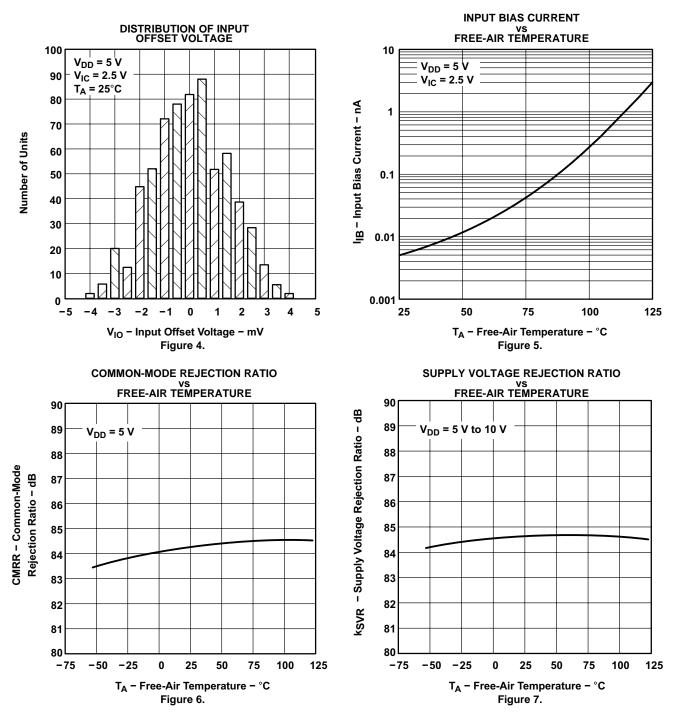
TLC393-Q1

SGLS198B-SEPTEMBER 2004-REVISED MAY 2013

TEXAS INSTRUMENTS

www.ti.com

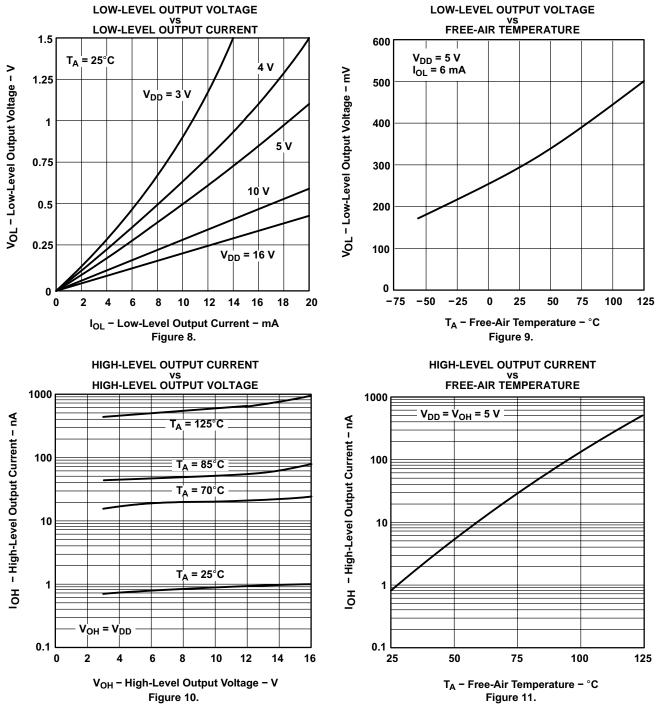
TYPICAL CHARACTERISTICS





SGLS198B-SEPTEMBER 2004-REVISED MAY 2013

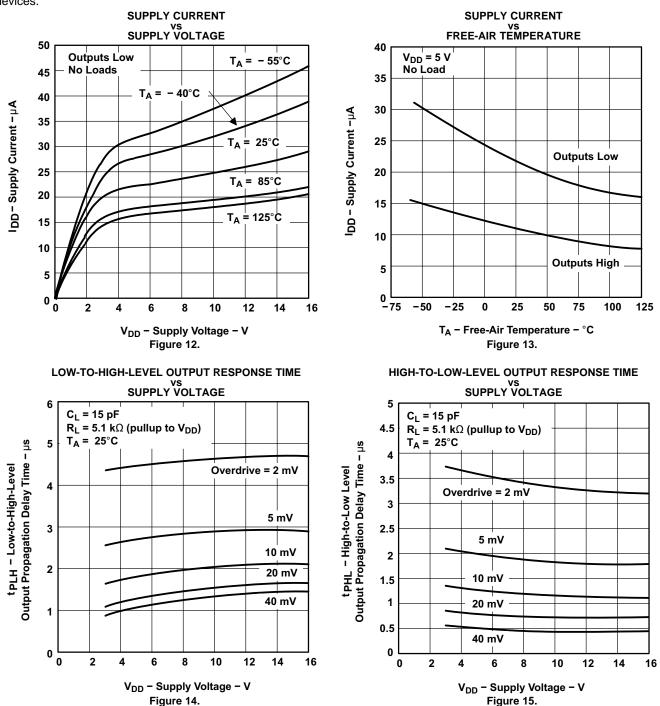
TYPICAL CHARACTERISTICS (continued)



TEXAS INSTRUMENTS

www.ti.com

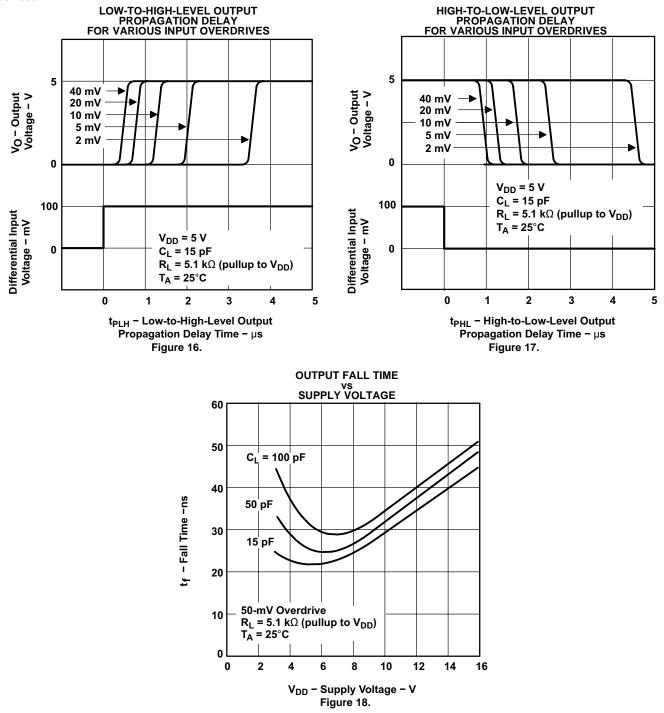
TYPICAL CHARACTERISTICS (continued)





SGLS198B-SEPTEMBER 2004-REVISED MAY 2013

TYPICAL CHARACTERISTICS (continued)





www.ti.com

APPLICATION INFORMATION

The input should always remain within the supply rails in order to avoid forward biasing the diodes in the electrostatic discharge (ESD) protection structure. If either input exceeds this range, the device will not be damaged as long as the input current is limited to less than 5 mA. To maintain the expected output state, the inputs must remain within the common-mode range. For example, at 25°C with $V_{DD} = 5$ V, both inputs must remain between -0.2 V and 4 V to assure proper device operation.

To assure reliable operation, the supply should be decoupled with a capacitor $(0.1-\mu F)$ positioned as close to the device as possible.

The TLC393 has internal ESD-protection circuits that prevent functional failures at voltages up to 2000 V as tested under MIL-STD-883C, Method 3015.2; however, care should be exercised in handling these devices, as exposure to ESD may result in the degradation of the device parametric performance.

	FIGURE
Pulse-Width-Modulated Motor Speed Controller	Figure 19
Enhanced Supply Supervisor	Figure 20
Two-Phase Nonoverlapping Clock Generator	Figure 21

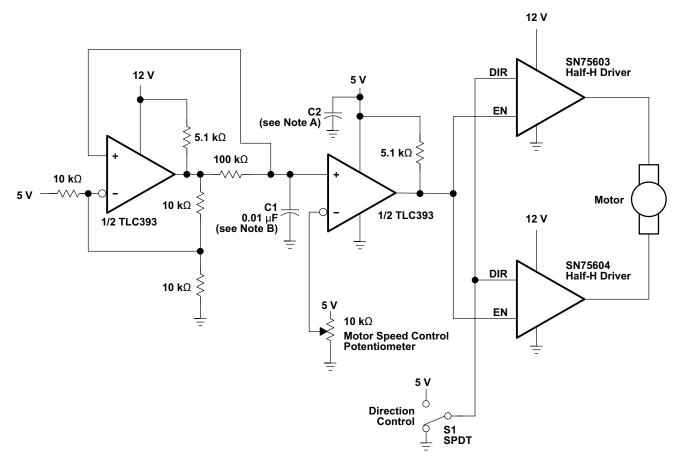


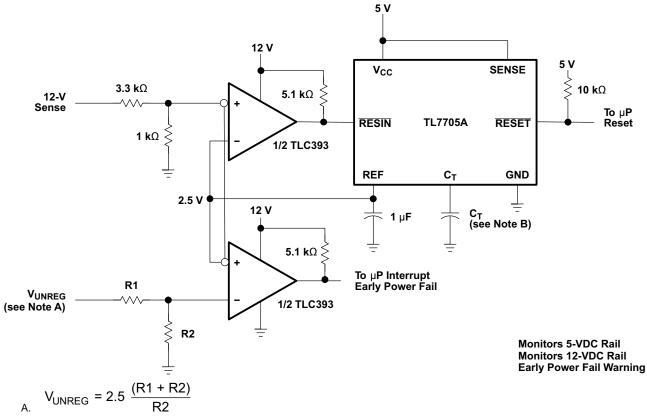
Table 2. Table of Applications

- A. The recommended minimum capacitance is 10 μF to eliminate common ground switching noise.
- B. Adjust C1 for change in oscillator frequency.

Figure 19. Pulse-Width-Modulated Motor Speed Controller



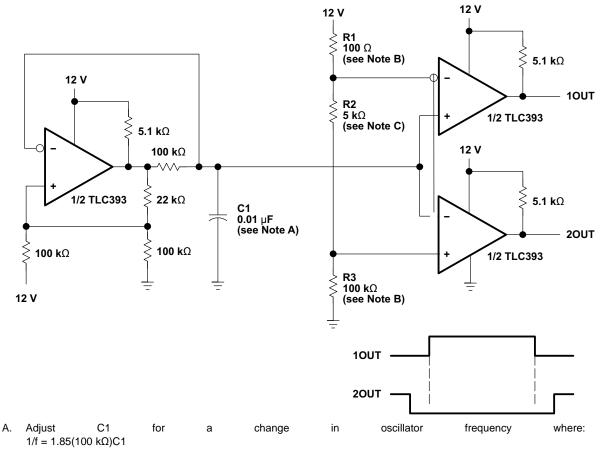




B. The value of C_T determines the time delay of reset.

Figure 20. Enhanced Supply Supervisor

www.ti.com



- B. Adjust R1 and R3 to change duty cycle
- C. Adjust R2 to change deadtime

Figure 21. Two-Phase Nonoverlapping Clock Generator

SGLS198B-SEPTEMBER 2004-REVISED MAY 2013

REVISION HISTORY

Cł	hanges from Original (September 2004) to Revision A Page						
•	Deleted Feature: Qualified in Accordance With AEC-Q100	1					
•	Deleted Feature: Customer-Specific Configuration Control	1					
Cł	Changes from Revision A (April 2008) to Revision B	Page					
	Changes from Revision A (April 2008) to Revision B Added Feature: AEC Q100 Qualified with the Following Results:						
•		1					



11-Apr-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing		Qty	(2)		(3)		(4)	
TLC393QDRG4Q1	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	C393Q1	Samples
TLC393QDRQ1	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	C393Q1	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TLC393-Q1 :



PACKAGE OPTION ADDENDUM

11-Apr-2013

Catalog: TLC393

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products		Applications	
Audio	www.ti.com/audio	Automotive and Transportation	www.ti.com/automotive
Amplifiers	amplifier.ti.com	Communications and Telecom	www.ti.com/communications
Data Converters	dataconverter.ti.com	Computers and Peripherals	www.ti.com/computers
DLP® Products	www.dlp.com	Consumer Electronics	www.ti.com/consumer-apps
DSP	dsp.ti.com	Energy and Lighting	www.ti.com/energy
Clocks and Timers	www.ti.com/clocks	Industrial	www.ti.com/industrial
Interface	interface.ti.com	Medical	www.ti.com/medical
Logic	logic.ti.com	Security	www.ti.com/security
Power Mgmt	power.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video
RFID	www.ti-rfid.com		
OMAP Applications Processors	www.ti.com/omap	TI E2E Community	e2e.ti.com
Wireless Connectivity	www.ti.com/wirelessconne	ectivity	

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2013, Texas Instruments Incorporated